



Welcome to E-XFL.COM

#### What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

#### Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

#### Details

Product Status	Obsolete
Core Processor	ST7
Core Size	8-Bit
Speed	8MHz
Connectivity	SPI
Peripherals	LVD, POR, PWM, WDT
Number of I/O	13
Program Memory Size	1KB (1K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	128 x 8
Voltage - Supply (Vcc/Vdd)	2.4V ~ 5.5V
Data Converters	A/D 5x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	16-SOIC (0.154", 3.90mm Width)
Supplier Device Package	16-SO
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/st7flites5y0m6tr

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

# REGISTER AND MEMORY MAP (Cont'd)

### Legend: x=undefined, R/W=read/write

# Table 2. Hardware Register Map

57

Address	Block	Register Label	Register Name	Reset Status	Remarks
0000h 0001h 0002h	Port A	PADR PADDR PAOR	Port A Data Register Port A Data Direction Register Port A Option Register	00h <sup>1)</sup> 00h 40h	R/W R/W R/W
0003h 0004h 0005h	Port B	PBDR PBDDR PBOR	Port B Data Register Port B Data Direction Register Port B Option Register	E0h <sup>1)</sup> 00h 00h	R/W R/W R/W <sup>2)</sup>
0006h to 000Ah			Reserved area (5 bytes)		
000Bh 000Ch	LITE TIMER	LTCSR LTICR	Lite Timer Control/Status Register Lite Timer Input Capture Register	xxh xxh	R/W Read Only
000Dh 000Eh 000Fh 0010h 0011h 0012h 0013h	AUTO-RELOAD TIMER	ATCSR CNTRH CNTRL ATRH ATRL PWMCR PWMOCSR	Timer Control/Status Register Counter Register High Counter Register Low Auto-Reload Register High Auto-Reload Register Low PWM Output Control Register PWM 0 Control/Status Register	00h 00h 00h 00h 00h 00h 00h	R/W Read Only Read Only R/W R/W R/W R/W
0014h to 0016h			Reserved area (3 bytes)		
0017h 0018h	AUTO-RELOAD TIMER	DCR0H DCR0L	PWM 0 Duty Cycle Register High PWM 0 Duty Cycle Register Low	00h 00h	R/W R/W
0019h to 002Eh			Reserved area (22 bytes)		
0002Fh	FLASH	FCSR	Flash Control/Status Register	00h	R/W
00030h	EEPROM	EECSR	Data EEPROM Control/Status Register	00h	R/W
0031h 0032h 0033h	SPI	SPIDR SPICR SPICSR	SPI Data I/O Register SPI Control Register SPI Control/Status Register	xxh 0xh 00h	R/W R/W R/W
0034h 0035h 0036h	ADC	ADCCSR ADCDR ADCAMP	A/D Control Status Register A/D Data Register A/D Amplifier Control Register	00h 00h 00h	R/W Read Only R/W
0037h	ITC	EICR	External Interrupt Control Register	00h	R/W
0038h 0039h	CLOCKS	MCCSR RCCR	Main Clock Control/Status Register RC oscillator Control Register	00h FFh	R/W R/W

# **4 FLASH PROGRAM MEMORY**

### 4.1 Introduction

The ST7 single voltage extended Flash (XFlash) is a non-volatile memory that can be electrically erased and programmed either on a byte-by-byte basis or up to 32 bytes in parallel.

The XFlash devices can be programmed off-board (plugged in a programming tool) or on-board using In-Circuit Programming or In-Application Programming.

The array matrix organisation allows each sector to be erased and reprogrammed without affecting other sectors.

#### 4.2 Main Features

5/

- ICP (In-Circuit Programming)
- IAP (In-Application Programming)
- ICT (In-Circuit Testing) for downloading and executing user application test patterns in RAM
- Sector 0 size configurable by option byte
- Read-out and write protection

#### **4.3 PROGRAMMING MODES**

The ST7 can be programmed in three different ways:

- Insertion in a programming tool. In this mode, FLASH sectors 0 and 1, option byte row and data EEPROM can be programmed or erased.
- In-Circuit Programming. In this mode, FLASH sectors 0 and 1, option byte row and data EEPROM can be programmed or erased without removing the device from the application board.
- In-Application Programming. In this mode, sector 1 and data EEPROM can be programmed or erased without removing the device from the application board and while the application is running.

#### 4.3.1 In-Circuit Programming (ICP)

ICP uses a protocol called ICC (In-Circuit Communication) which allows an ST7 plugged on a printed circuit board (PCB) to communicate with an external programming device connected via cable. ICP is performed in three steps:

Switch the ST7 to ICC mode (In-Circuit Communications). This is done by driving a specific signal sequence on the ICCCLK/DATA pins while the RESET pin is pulled low. When the ST7 enters ICC mode, it fetches a specific RESET vector which points to the ST7 System Memory containing the ICC protocol routine. This routine enables the ST7 to receive bytes from the ICC interface.

- Download ICP Driver code in RAM from the ICCDATA pin
- Execute ICP Driver code in RAM to program the FLASH memory

Depending on the ICP Driver code downloaded in RAM, FLASH memory programming can be fully customized (number of bytes to program, program locations, or selection of the serial communication interface for downloading).

#### 4.3.2 In Application Programming (IAP)

This mode uses an IAP Driver program previously programmed in Sector 0 by the user (in ICP mode).

This mode is fully controlled by user software. This allows it to be adapted to the user application, (user-defined strategy for entering programming mode, choice of communications protocol used to fetch the data to be stored etc.)

IAP mode can be used to program any memory areas except Sector 0, which is write/erase protected to allow recovery in case errors occur during the programming operation.

# CPU REGISTERS (Cont'd) Stack Pointer (SP)

#### Read/Write

57/

Reset Value: 00 FFh

15							8
0	0	0	0	0	0	0	0
7							0
1	1	SP5	SP4	SP3	SP2	SP1	SP0

The Stack Pointer is a 16-bit register which is always pointing to the next free location in the stack. It is then decremented after data has been pushed onto the stack and incremented before data is popped from the stack (see Figure 12).

Since the stack is 64 bytes deep, the 10 most significant bits are forced by hardware. Following an MCU Reset, or after a Reset Stack Pointer instruction (RSP), the Stack Pointer contains its reset value (the SP5 to SP0 bits are set) which is the stack higher address. The least significant byte of the Stack Pointer (called S) can be directly accessed by a LD instruction.

**Note:** When the lower limit is exceeded, the Stack Pointer wraps around to the stack upper limit, without indicating the stack overflow. The previously stored information is then overwritten and therefore lost. The stack also wraps in case of an underflow.

The stack is used to save the return address during a subroutine call and the CPU context during an interrupt. The user may also directly manipulate the stack by means of the PUSH and POP instructions. In the case of an interrupt, the PCL is stored at the first location pointed to by the SP. Then the other registers are stored in the next locations as shown in Figure 12.

- When an interrupt is received, the SP is decremented and the context is pushed on the stack.
- On return from interrupt, the SP is incremented and the context is popped from the stack.

A subroutine call occupies two locations and an interrupt five locations in the stack area.



# SUPPLY, RESET AND CLOCK MANAGEMENT (Cont'd)



<u>ل</u>حک

Figure 14. Clock Management Block Diagram

# SYSTEM INTEGRITY MANAGEMENT (Cont'd)

## 8.4.3 Low Power Modes

Mode	Description
WAIT	No effect on SI. AVD interrupts cause the device to exit from Wait mode.
HALT	The SICSR register is frozen. The AVD remains active but the AVD inter- rupt cannot be used to exit from Halt mode.

## 8.4.3.1 Interrupts

<u>ل</u>حک

The AVD interrupt event generates an interrupt if the corresponding Enable Control Bit (AVDIE) is set and the interrupt mask in the CC register is reset (RIM instruction).

Interrupt Event	Event Flag	Enable Control Bit	Exit from Wait	Exit from Halt
AVD event	AVDF	AVDIE	Yes	No

# 10 I/O PORTS

# **10.1 INTRODUCTION**

The I/O ports offer different functional modes: – transfer of data through digital inputs and outputs

- and for specific pins:
- external interrupt generation
- alternate signal input/output for the on-chip peripherals.

An I/O port contains up to 8 pins. Each pin can be programmed independently as digital input (with or without interrupt generation) or digital output.

# **10.2 FUNCTIONAL DESCRIPTION**

Each port has 2 main registers:

- Data Register (DR)
- Data Direction Register (DDR)
- and one optional register:
- Option Register (OR)

Each I/O pin may be programmed using the corresponding register bits in the DDR and OR registers: bit X corresponding to pin X of the port. The same correspondence is used for the DR register.

The following description takes into account the OR register, (for specific ports which do not provide this register refer to the I/O Port Implementation section). The generic I/O block diagram is shown in Figure 29

#### 10.2.1 Input Modes

The input configuration is selected by clearing the corresponding DDR register bit.

In this case, reading the DR register returns the digital value applied to the external I/O pin.

Different input modes can be selected by software through the OR register.

**Note**: Writing the DR register modifies the latch value but does not affect the pin status.

#### External interrupt function

When an I/O is configured as Input with Interrupt, an event on this I/O can generate an external interrupt request to the CPU.

Each pin can independently generate an interrupt request. The interrupt sensitivity is independently programmable using the sensitivity bits in the EICR register.

Each external interrupt vector is linked to a dedicated group of I/O port pins (see pinout description and interrupt section). If several input pins are selected simultaneously as interrupt source, these are logically ANDed. For this reason if one of the interrupt pins is tied low, it may mask the others.

External interrupts are hardware interrupts. Fetching the corresponding interrupt vector automatically clears the request latch. Changing the sensitivity of a particular external interrupt clears this pending interrupt. This can be used to clear unwanted pending interrupts.

#### **Spurious interrupts**

When enabling/disabling an external interrupt by setting/resetting the related OR register bit, a spurious interrupt is generated if the pin level is low and its edge sensitivity includes falling/rising edge. This is due to the edge detector input which is switched to '1' when the external interrupt is disabled by the OR register.

To avoid this unwanted interrupt, a "safe" edge sensitivity (rising edge for enabling and falling edge for disabling) has to be selected before changing the OR register bit and configuring the appropriate sensitivity again.

**Caution:** In case a pin level change occurs during these operations (asynchronous signal input), as interrupts are generated according to the current sensitivity, it is advised to disable all interrupts before and to reenable them after the complete previous sequence in order to avoid an external interrupt occurring on the unwanted edge.

This corresponds to the following steps:

- 1. To enable an external interrupt:
  - set the interrupt mask with the SIM instruction (in cases where a pin level change could occur)
  - select rising edge
  - enable the external interrupt through the OR register
  - select the desired sensitivity if different from rising edge
  - reset the interrupt mask with the RIM instruction (in cases where a pin level change could occur)
- 2. To disable an external interrupt:
  - set the interrupt mask with the SIM instruction SIM (in cases where a pin level change could occur)
  - select falling edge
  - disable the external interrupt through the OR register
  - select rising edge



# I/O PORTS (Cont'd)

# Figure 29. I/O Port General Block Diagram



# Table 9. I/O Port Mode Options

Configuration Mode		<b>Bull-Un</b>	P-Buffor	Diodes	
		i un-op	i -Dunei	to V <sub>DD</sub>	to V <sub>SS</sub>
Input	Floating with/without Interrupt	Off	0#	On	On
input	Pull-up with/without Interrupt	On			
Output	Push-pull	Off	On	On	
Culput	Open Drain (logic level)		Off		

Legend: NI - not implemented Off - implemented not activated

On - implemented and activated



# 11.2 12-BIT AUTORELOAD TIMER (AT)

### 11.2.1 Introduction

The 12-bit Autoreload Timer can be used for general-purpose timing functions. It is based on a freerunning 12-bit upcounter with a PWM output channel.

#### 11.2.2 Main Features

- 12-bit upcounter with 12-bit autoreload register (ATR)
- Maskable overflow interrupt

# Figure 34. Block Diagram

<u>ل</u>حک

- PWM signal generator
- Frequency range 2KHz-4MHz (@ 8 MHz f<sub>CPU</sub>)
  - Programmable duty-cycle
  - Polarity control
  - Maskable Compare interrupt
- Output Compare Function



#### 12-BIT AUTORELOAD TIMER (Cont'd) AUTO RELOAD REGISTER (ATRH) Read / Write

Reset Value: 0000 0000 (00h)

15							8
0	0	0	0	ATR11	ATR10	ATR9	ATR8

#### AUTO RELOAD REGISTER (ATRL) Read / Write

Reset Value: 0000 0000 (00h)

7							0
ATR7	ATR6	ATR5	ATR4	ATR3	ATR2	ATR1	ATR0

Bits 15:12 = Reserved, must be kept cleared.

Bits 11:0 = **ATR[11:0]** Autoreload Register.

This is a 12-bit register which is written by software. The ATR register value is automatically loaded into the upcounter when an overflow occurs. The register value is used to set the PWM frequency.

# **PWM0 DUTY CYCLE REGISTER HIGH (DCR0H)**

Read / Write

Reset Value: 0000 0000 (00h)

15							8
0	0	0	0	DCR11	DCR10	DCR9	DCR8

# PWM0 DUTY CYCLE REGISTER LOW (DCR0L)

Read / Write Reset Value: 0000 0000 (00h)

7							0
DCR7	DCR6	DCR5	DCR4	DCR3	DCR2	DCR1	DCR0

Bits 15:12 = Reserved, must be kept cleared.

Bits 11:0 = **DCR[11:0]** *PWMx Duty Cycle Value* This 12-bit value is written by software. The high register must be written first.

In PWM mode (OE0=1 in the PWMCR register) the DCR[11:0] bits define the duty cycle of the PWM0 output signal (see Figure 35). In Output Compare mode, (OE0=0 in the PWMCR register) they define the value to be compared with the 12-bit upcounter value.

#### PWM0 CONTROL/STATUS REGISTER (PWM0CSR) Read / Write

Reset Value: 0000 0000 (00h)

7							0
0	0	0	0	0	0	OP0	CMPF0

Bit 7:2= Reserved, must be kept cleared.

#### Bit 1 = OP0 PWM0 Output Polarity.

This bit is read/write by software and cleared by hardware after a reset. This bit selects the polarity of the PWM0 signal.

0: The PWM0 signal is not inverted.

1: The PWM0 signal is inverted.

#### Bit 0 = CMPF0 PWM0 Compare Flag.

This bit is set by hardware and cleared by software by reading the PWM0CSR register. It indicates that the upcounter value matches the DCR0 register value.

0: Upcounter value does not match DCR value.

1: Upcounter value matches DCR value.

# 12-BIT AUTORELOAD TIMER (Cont'd)

# PWM OUTPUT CONTROL REGISTER (PWMCR)

Read/Write

Reset Value: 0000 0000 (00h)

7							0
0	0	0	0	0	0	0	OE0

### Table 14. Register Map and Reset Values

Bits 7:1 = Reserved, must be kept cleared.

Bit 0 = **OE0** *PWM0 Output enable*.

This bit is set and cleared by software.0: PWM0 output Alternate Function disabled (I/O pin free for general purpose I/O)

<u>/۲۸</u>

1: PWM0 output enabled

Address (Hex.)	Register Label	7	6	5	4	3	2	1	0
0D	ATCSR Reset Value	0	0	0	CK1 0	CK0 0	OVF 0	OVFIE 0	CMPIE 0
0E	CNTRH Reset Value	0	0	0	0	CN11 0	CN10 0	CN9 0	CN8 0
0F	CNTRL Reset Value	CN7 0	CN6 0	CN5 0	CN4 0	CN3 0	CN2 0	CN1 0	CN0 0
10	ATRH Reset Value	0	0	0	0	ATR11 0	ATR10 0	ATR9 0	ATR8 0
11	ATRL Reset Value	ATR7 0	ATR6 0	ATR5 0	ATR4 0	ATR3 0	ATR2 0	ATR1 0	ATR0 0
12	PWMCR Reset Value	0	0	0	0	0	0	0	OE0 0
13	PWM0CSR Reset Value	0	0	0	0	0	0	OP 0	CMPF0 0
17	DCR0H Reset Value	0	0	0	0	DCR11 0	DCR10 0	DCR9 0	DCR8 0
18	DCR0L Reset Value	DCR7 0	DCR6 0	DCR5 0	DCR4 0	DCR3 0	DCR2 0	DCR1 0	DCR0 0

# ST7 ADDRESSING MODES (cont'd)

### 12.1.1 Inherent

All Inherent instructions consist of a single byte. The opcode fully specifies all the required information for the CPU to process the operation.

Inherent Instruction	Function			
NOP	No operation			
TRAP	S/W Interrupt			
WFI	Wait For Interrupt (Low Power Mode)			
HALT	Halt Oscillator (Lowest Power Mode)			
RET	Subroutine Return			
IRET	Interrupt Subroutine Return			
SIM	Set Interrupt Mask			
RIM	Reset Interrupt Mask			
SCF	Set Carry Flag			
RCF	Reset Carry Flag			
RSP	Reset Stack Pointer			
LD	Load			
CLR	Clear			
PUSH/POP	Push/Pop to/from the stack			
INC/DEC	Increment/Decrement			
TNZ	Test Negative or Zero			
CPL, NEG	1 or 2 Complement			
MUL	Byte Multiplication			
SLL, SRL, SRA, RLC, RRC	Shift and Rotate Operations			
SWAP	Swap Nibbles			

# 12.1.2 Immediate

Immediate instructions have 2 bytes, the first byte contains the opcode, the second byte contains the operand value.

Immediate Instruction	Function
LD	Load
СР	Compare
BCP	Bit Compare
AND, OR, XOR	Logical Operations
ADC, ADD, SUB, SBC	Arithmetic Operations

### 12.1.3 Direct

In Direct instructions, the operands are referenced by their memory address.

The direct addressing mode consists of two submodes:

## **Direct (Short)**

The address is a byte, thus requires only 1 byte after the opcode, but only allows 00 - FF addressing space.

#### Direct (Long)

The address is a word, thus allowing 64 Kbyte addressing space, but requires 2 bytes after the opcode.

#### 12.1.4 Indexed (No Offset, Short, Long)

In this mode, the operand is referenced by its memory address, which is defined by the unsigned addition of an index register (X or Y) with an offset.

The indirect addressing mode consists of three submodes:

#### Indexed (No Offset)

There is no offset (no extra byte after the opcode), and allows 00 - FF addressing space.

#### Indexed (Short)

The offset is a byte, thus requires only 1 byte after the opcode and allows 00 - 1FE addressing space.

#### Indexed (Long)

The offset is a word, thus allowing 64 Kbyte addressing space and requires 2 bytes after the opcode.

# 12.1.5 Indirect (Short, Long)

The required data byte to do the operation is found by its memory address, located in memory (pointer).

The pointer address follows the opcode. The indirect addressing mode consists of two submodes:

#### Indirect (Short)

The pointer address is a byte, the pointer size is a byte, thus allowing 00 - FF addressing space, and requires 1 byte after the opcode.

#### Indirect (Long)

The pointer address is a byte, the pointer size is a word, thus allowing 64 Kbyte addressing space, and requires 1 byte after the opcode.



# INSTRUCTION GROUPS (cont'd)

57

Mnemo	Description	Function/Example	Dst	Src	ŀ	1	Ι	Ν	Z	С
ADC	Add with Carry	A = A + M + C	А	М	ŀ	H		Ν	Z	С
ADD	Addition	A=A+M	А	М	H	ł		Ν	Z	С
AND	Logical And	A = A . M	А	М				Ν	Z	
BCP	Bit compare A, Memory	tst (A . M)	А	М				Ν	Z	
BRES	Bit Reset	bres Byte, #3	М							
BSET	Bit Set	bset Byte, #3	М							
BTJF	Jump if bit is false (0)	btjf Byte, #3, Jmp1	М							С
BTJT	Jump if bit is true (1)	btjt Byte, #3, Jmp1	М							С
CALL	Call subroutine									
CALLR	Call subroutine relative									
CLR	Clear		reg, M					0	1	
СР	Arithmetic Compare	tst(Reg - M)	reg	М				Ν	Z	С
CPL	One Complement	A = FFH-A	reg, M					Ν	Z	1
DEC	Decrement	dec Y	reg, M					Ν	Z	
HALT	Halt						0			
IRET	Interrupt routine return	Pop CC, A, X, PC			ł	4	Ι	Ν	Z	С
INC	Increment	inc X	reg, M					Ν	Z	
JP	Absolute Jump	jp [TBL.w]								
JRA	Jump relative always									
JRT	Jump relative									
JRF	Never jump	jrf *								
JRIH	Jump if ext. interrupt = 1									
JRIL	Jump if ext. interrupt = 0									
JRH	Jump if H = 1	H = 1 ?								
JRNH	Jump if H = 0	H = 0 ?								
JRM	Jump if I = 1	I = 1 ?								
JRNM	Jump if I = 0	I = 0 ?								
JRMI	Jump if N = 1 (minus)	N = 1 ?								
JRPL	Jump if N = 0 (plus)	N = 0 ?								
JREQ	Jump if Z = 1 (equal)	Z = 1 ?								
JRNE	Jump if Z = 0 (not equal)	Z = 0 ?								
JRC	Jump if C = 1	C = 1 ?								
JRNC	Jump if C = 0	C = 0 ?								
JRULT	Jump if C = 1	Unsigned <								
JRUGE	Jump if C = 0	Jmp if unsigned >=								
JRUGT	Jump if $(C + Z = 0)$	Unsigned >								

# **13 ELECTRICAL CHARACTERISTICS**

# **13.1 PARAMETER CONDITIONS**

Unless otherwise specified, all voltages are referred to  $\ensuremath{\mathsf{V}_{SS}}\xspace.$ 

#### 13.1.1 Minimum and Maximum values

Unless otherwise specified the minimum and maximum values are guaranteed in the worst conditions of ambient temperature, supply voltage and frequencies by tests in production on 100% of the devices with an ambient temperature at  $T_A=25^{\circ}C$  and  $T_A=T_Amax$  (given by the selected temperature range).

Data based on characterization results, design simulation and/or technology characteristics are indicated in the table footnotes and are not tested in production. Based on characterization, the minimum and maximum values refer to sample tests and represent the mean value plus or minus three times the standard deviation (mean $\pm 3\Sigma$ ).

#### 13.1.2 Typical values

Unless otherwise specified, typical data are based on  $T_A=25\,^\circ\text{C}, V_{DD}=5V$  (for the  $4.5V{\le}V_{DD}{\le}5.5V$  voltage range),  $V_{DD}=3.3V$  (for the  $3V{\le}V_{DD}{\le}3.6V$  voltage range) and  $V_{DD}=2.7V$  (for the  $2.4V{\le}V_{DD}{\le}3V$  voltage range). They are given only as design guidelines and are not tested.

# 13.1.3 Typical curves

57

Unless otherwise specified, all typical curves are given only as design guidelines and are not tested.

#### 13.1.4 Loading capacitor

The loading conditions used for pin parameter measurement are shown in Figure 46.

# Figure 46. Pin loading conditions



#### 13.1.5 Pin input voltage

The input voltage measurement on a pin of the device is described in Figure 47.

#### Figure 47. Pin input voltage



# 13.3.2 Operating Conditions with Low Voltage Detector (LVD)

 $T_A = -40$  to 85°C, unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>IT+(LVD)</sub>	Reset release threshold (V <sub>DD</sub> rise)	High Threshold Med. Threshold Low Threshold	4.00 <sup>1)</sup> 3.40 <sup>1)</sup> 2.65 <sup>1)</sup>	4.25 3.60 2.90	4.50 3.80 3.15	V
V <sub>IT-(LVD)</sub>	Reset generation threshold $(V_{DD}$ fall)	High Threshold Med. Threshold Low Threshold	3.80 3.20 2.40	4.05 3.40 2.70	4.30 <sup>1)</sup> 3.65 <sup>1)</sup> 2.90 <sup>1)</sup>	v
V <sub>hys</sub>	LVD voltage threshold hysteresis	V <sub>IT+(LVD)</sub> -V <sub>IT-(LVD)</sub>		200		mV
Vt <sub>POR</sub>	V <sub>DD</sub> rise time rate <sup>2)</sup>		20		20000	μs/V
t <sub>g(VDD)</sub>	Filtered glitch delay on $V_{DD}$	Not detected by the LVD			150	ns
I <sub>DD(LVD</sub> )	LVD/AVD current consumption			220		μA

Notes:

**1.** Not tested in production.

**2.** Not tested in production. The  $V_{DD}$  rise time rate condition is needed to ensure a correct device power-on and LVD reset. When the  $V_{DD}$  slope is outside these values, the LVD may not ensure a proper reset of the MCU.

# 13.3.3 Auxiliary Voltage Detector (AVD) Thresholds

 $T_A = -40$  to 85°C, unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	1->0 AVDE flag toggle threshold	High Threshold	4.40	4.70	5.00	
V <sub>IT+(AVD)</sub>	(V <sub>DD</sub> rise)	Med. Threshold	3.90	4.10	4.30	
		Low Threshold	3.20	3.40	3.60	v
	0=>1 AVDF flag toggle threshold (V <sub>DD</sub> fall)	High Threshold	4.30	4.60	4.90	v
V <sub>IT-(AVD)</sub>		Med. Threshold	3.70	3.90	4.10	
		Low Threshold	2.90	3.20	3.40	
V <sub>hys</sub>	AVD voltage threshold hysteresis	V <sub>IT+(AVD)</sub> -V <sub>IT-(AVD)</sub>		150		mV
$\Delta V_{IT}$	Voltage drop between AVD flag set and LVD reset activation	V <sub>DD</sub> fall		0.45		V

47/

# 13.3.4 Internal RC Oscillator and PLL

The ST7 internal clock can be supplied by an internal RC oscillator and PLL (selectable by option byte).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>DD(RC)</sub>	Internal RC Oscillator operating voltage		2.4		5.5	
V <sub>DD(x4PLL)</sub>	x4 PLL operating voltage		2.4		3.3	V
V <sub>DD(x8PLL)</sub>	x8 PLL operating voltage		3.3		5.5	
t <sub>STARTUP</sub>	PLL Startup time			60		PLL input clock (f <sub>PLL</sub> ) cycles

The RC oscillator and PLL characteristics are temperature-dependent and are grouped in two tables. 13.3.4.1 Devices with "6" order code suffix (tested for  $T_A = -40$  to  $+85^{\circ}$ C) @  $V_{DD} = 4.5$  to 5.5V

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
£ 1)	Internal RC oscillator fre-	RCCR = FF (reset value), T <sub>A</sub> =25°C, V <sub>DD</sub> =5V		760		L 니 ㅋ
'RC '	quency	RCCR = RCCR0 <sup>2</sup> ),T <sub>A</sub> =25°C, V <sub>DD</sub> =5V		1000		КПZ
	Accuracy of Internal RC	T <sub>A</sub> =25°C,V <sub>DD</sub> =4.5 to 5.5V	-1		+1	%
ACC <sub>RC</sub>	oscillator with	T <sub>A</sub> =-40 to +85°C, V <sub>DD</sub> =5V	-5		+2	%
	RCCR=RCCR0 <sup>2)</sup>	T <sub>A</sub> =0 to +85°C, V <sub>DD</sub> =4.5 to 5.5V	-2 <sup>3)</sup>		+2 <sup>3)</sup>	%
I <sub>DD(RC)</sub>	RC oscillator current con- sumption	T <sub>A</sub> =25°C,V <sub>DD</sub> =5V		970 <sup>3)</sup>		μA
t <sub>su(RC)</sub>	RC oscillator setup time	T <sub>A</sub> =25°C,V <sub>DD</sub> =5V			10 <sup>2)</sup>	μS
f <sub>PLL</sub>	x8 PLL input clock			1 <sup>3)</sup>		MHz
t <sub>LOCK</sub>	PLL Lock time <sup>5)</sup>			2		ms
t <sub>STAB</sub>	PLL Stabilization time <sup>5)</sup>			4		ms
ACC		$f_{RC} = 1MHz@T_A=25°C, V_{DD}=4.5 to 5.5V$		0.1 <sup>4)</sup>		%
ACOPLL	XOT LL Accuracy	$f_{RC} = 1MHz@T_A=-40 \text{ to } +85^{\circ}C, V_{DD}=5V$		0.1 <sup>4)</sup>		%
t <sub>w(JIT)</sub>	PLL jitter period	f <sub>RC</sub> = 1MHz		8 <sup>6)</sup>		kHz
JIT <sub>PLL</sub>	PLL jitter (∆f <sub>CPU</sub> /f <sub>CPU</sub> )			1 <sup>6)</sup>		%
I <sub>DD(PLL)</sub>	PLL current consumption	T <sub>A</sub> =25°C		600 <sup>3)</sup>		μA

#### Notes:

1. If the RC oscillator clock is selected, to improve clock stability and frequency accuracy, it is recommended to place a decoupling capacitor, typically 100nF, between the  $V_{DD}$  and  $V_{SS}$  pins as close as possible to the ST7 device.

2. See "INTERNAL RC OSCILLATOR ADJUSTMENT" on page 24

3. Data based on characterization results, not tested in production

4. Averaged over a 4ms period. After the LOCKED bit is set, a period of t<sub>STAB</sub> is required to reach ACC<sub>PLL</sub> accuracy

5. After the LOCKED bit is set ACC<sub>PLL</sub> is max. 10% until t<sub>STAB</sub> has elapsed. See Figure 13 on page 25.

6. Guaranteed by design.

# Figure 69. Typical V<sub>DD</sub>-V<sub>OH</sub> at V<sub>DD</sub>=2.7V



# Figure 70. Typical $V_{DD}$ - $V_{OH}$ at $V_{DD}$ =3V



Figure 73. Typical V<sub>OL</sub> vs. V<sub>DD</sub> (standard I/Os)







Figure 72. Typical V<sub>DD</sub>-V<sub>OH</sub> at V<sub>DD</sub>=5V



57

# Figure 74. Typical $V_{OL}$ vs. $V_{DD}$ (high-sink I/Os)



Figure 75. Typical V<sub>DD</sub>-V<sub>OH</sub> vs. V<sub>DD</sub>

57



# ADC CHARACTERISTICS (Cont'd)

#### ADC Accuracy with V<sub>DD</sub>=5.0V

 $T_A = -40^{\circ}C$  to 85°C, unless otherwise specified

Symbol	Parameter	Conditions	Тур	Мах	Unit
ET	Total unadjusted error <sup>2)</sup>		±1		
EO	Offset error <sup>2)</sup>			-0.5 / +1	
E <sub>G</sub>	Gain Error <sup>2)</sup>	f <sub>CPU</sub> =4MHz, f <sub>ADC</sub> =2MHz, V <sub>DD</sub> =5.0V		±1	LSB
E <sub>D</sub>	Differential linearity error <sup>2)</sup>			±1 <sup>1)</sup>	
EL	Integral linearity error <sup>2)</sup>			±1 <sup>1)</sup>	
E <sub>T</sub>	Total unadjusted error <sup>2)</sup>		±2		
E <sub>O</sub>	Offset error <sup>2)</sup>			-0.5 / 3.5	
E <sub>G</sub>	Gain Error <sup>2)</sup>	f <sub>CPU</sub> =8MHz, f <sub>ADC</sub> =4MHz, V <sub>DD</sub> =5.0V		-2 / 0	LSB
ED	Differential linearity error <sup>2)</sup>			±1 <sup>1)</sup>	
EL	Integral linearity error <sup>2)</sup>			±1 <sup>1)</sup>	

#### Notes:

1. Data based on characterization results over the whole temperature range, monitored in production.

2. Injecting negative current on any of the analog input pins significantly reduces the accuracy of any conversion being performed on any analog input.

Analog pins can be protected against negative injection by adding a Schottky diode (pin to ground). Injecting negative current on digital input pins degrades ADC accuracy especially if performed on a pin close to the analog input pins. Any positive injection current within the limits specified for  $I_{INJ(PIN)}$  and  $\Sigma I_{INJ(PIN)}$  in Section 13.8 does not affect the ADC accuracy.

\_

# ADC CHARACTERISTICS (Cont'd)

57



#### Figure 84. ADC Accuracy Characteristics with Amplifier disabled

#### Figure 85. ADC Accuracy Characteristics with Amplifier enabled



**Note:** When the AMPSEL bit in the ADCDRL register is set, it is mandatory that  $f_{ADC}$  be less than or equal to 2 MHz. (if  $f_{CPU}$ =8MHz. then SPEED=0, SLOW=1).

# Table 24. ST7 Application Notes

IDENTIFICATION	DESCRIPTION
AN1947	ST7MC PMAC SINE WAVE MOTOR CONTROL SOFTWARE LIBRARY
GENERAL PURPC	DSE
AN1476	LOW COST POWER SUPPLY FOR HOME APPLIANCES
AN1526	ST7FLITE0 QUICK REFERENCE NOTE
AN1709	EMC DESIGN FOR ST MICROCONTROLLERS
AN1752	ST72324 QUICK REFERENCE NOTE
PRODUCT EVALU	ATION
AN 910	PERFORMANCE BENCHMARKING
AN 990	ST7 BENEFITS VS INDUSTRY STANDARD
AN1077	OVERVIEW OF ENHANCED CAN CONTROLLERS FOR ST7 AND ST9 MCUS
AN1086	U435 CAN-DO SOLUTIONS FOR CAR MULTIPLEXING
AN1103	IMPROVED B-EMF DETECTION FOR LOW SPEED, LOW VOLTAGE WITH ST72141
AN1150	BENCHMARK ST72 VS PC16
AN1151	PERFORMANCE COMPARISON BETWEEN ST72254 & PC16F876
AN1278	LIN (LOCAL INTERCONNECT NETWORK) SOLUTIONS
PRODUCT MIGRA	TION
AN1131	MIGRATING APPLICATIONS FROM ST72511/311/214/124 TO ST72521/321/324
AN1322	MIGRATING AN APPLICATION FROM ST7263 REV.B TO ST7263B
AN1365	GUIDELINES FOR MIGRATING ST72C254 APPLICATIONS TO ST72F264
AN1604	HOW TO USE ST7MDT1-TRAIN WITH ST72F264
AN2200	GUIDELINES FOR MIGRATING ST7LITE1X APPLICATIONS TO ST7FLITE1XB
PRODUCT OPTIM	IZATION
AN 982	USING ST7 WITH CERAMIC RESONATOR
AN1014	HOW TO MINIMIZE THE ST7 POWER CONSUMPTION
AN1015	SOFTWARE TECHNIQUES FOR IMPROVING MICROCONTROLLER EMC PERFORMANCE
AN1040	MONITORING THE VBUS SIGNAL FOR USB SELF-POWERED DEVICES
AN1070	ST7 CHECKSUM SELF-CHECKING CAPABILITY
AN1181	ELECTROSTATIC DISCHARGE SENSITIVE MEASUREMENT
AN1324	CALIBRATING THE RC OSCILLATOR OF THE ST7FLITE0 MCU USING THE MAINS
AN1502	EMULATED DATA EEPROM WITH ST7 HDFLASH MEMORY
AN1529	EXTENDING THE CURRENT & VOLTAGE CAPABILITY ON THE ST7265 VDDF SUPPLY
AN1530	ACCURATE TIMEBASE FOR LOW-COST ST7 APPLICATIONS WITH INTERNAL RC OSCILLATOR
AN1605	USING AN ACTIVE RC TO WAKEUP THE ST7LITE0 FROM POWER SAVING MODE
AN1636	UNDERSTANDING AND MINIMIZING ADC CONVERSION ERRORS
AN1828	PIR (PASSIVE INFRARED) DETECTOR USING THE ST7FLITE05/09/SUPERLITE
AN1946	SENSORLESS BLDC MOTOR CONTROL AND BEMF SAMPLING METHODS WITH ST7MC
AN1953	PFC FOR ST7MC STARTER KIT
AN1971	ST7LITE0 MICROCONTROLLED BALLAST
PROGRAMMING A	AND TOOLS
AN 978	ST7 VISUAL DEVELOP SOFTWARE KEY DEBUGGING FEATURES
AN 983	KEY FEATURES OF THE COSMIC ST7 C-COMPILER PACKAGE
AN 985	EXECUTING CODE IN ST7 RAM
AN 986	USING THE INDIRECT ADDRESSING MODE WITH ST7
AN 987	ST7 SERIAL TEST CONTROLLER PROGRAMMING
AN 988	STARTING WITH ST7 ASSEMBLY TOOL CHAIN
AN1039	ST7 MATH UTILITY ROUTINES